



Features

- Single-Channel Power Distribution Switch
- Programmable Current Limit in 0.4A~2A Output Current
- Enable polarity: Active High
- 2.4V to 5.5V Supply Range
- Under-Voltage Lockout
- -40°C to +85°C Ambient Temperature Range

Applications

- Set-Top Boxes
- Wi-Fi Router/AP
- USB 3G Datacard/ USB Dongle
- High-Definition Digital TVs

General Description

- Accurate Current Limit
- 15µA Quiescent Current
- 80mΩ MOSFET
- Thermal-Shutdown Protection
- Built-In Soft Start
- Available in SOT23-5 Package
- ONT Boxes
- USB Ports and Hubs, Laptops, and Desktops
- Smartphone and PDA
- MiniPCI Accessories

The RY2121 Power Distribution Switch features internal current limiting to prevent damage to host devices due to faulty load conditions. The RY2121 develops ultra-low on-resistance switch with programmable current limiting to protect the power source from over current and short circuit conditions. It integrates the over temperature protection and discharges the output capacitor during the shutdown. The RY2121 is available in SOT23-5 package.

Typical Application Circuit



Basic Application Circuit



Pin Description

Pin Configuration



Top Marking: ME<u>YLL</u> (device code: ME, Y=year code, LL= lot number code)

Pin Description

Pin	Name	Function			
1	OUT	Output Pin.			
2	GND	Ground Pin.			
3	SET	Current limit programming Pin. Connect a resistor R_{SET} from this pin to GND to program the current limit.			
4	EN	ON/OFF control. Pull High to enable IC, do not float.			
5	IN	Power Supply Pin			

Order Information ⁽¹⁾

Marking	Part No.	Model	Description	Package	T/R Qty
ME <u>YLL</u>	70702013	RY2121	RY2121 1CH Current Limited IC, V_{IN} 2.4V- 5.5V, I_{LIM} ADJ, Active High, SOT23-5	SOT23-5	3000PCS

Note (1): All RYCHIP parts are Pb-Free and adhere to the RoHS directive.



Specifications

Absolute Maximum Ratings (1) (2)

Item	Min	Max	Unit
All pins voltage	-0.3	6	V
Power dissipation ⁽³⁾	Internally Lim	nited	
Operating junction temperature, T _J	-40	150	°C
Storage temperature, T _{stg}	-55	150	°C
Lead Temperature (Soldering, 10sec.)		260	°C

Note (1): Exceeding these ratings may damage the device.

Note (2): The device is not guaranteed to function outside of its operating conditions.

Note (3): The maximum allowable power dissipation is a function of the maximum junction temperature, $T_{J(MAX)}$, the junction-to-ambient thermal resistance, $R_{\theta JA}$, and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D(MAX)} = (T_{J(MAX)} - T_A)/R_{\theta JA}$. Exceeding the maximum allowable power dissipation causes excessive die temperature, and the regulator goes into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at $T_J=150^{\circ}C$ (typical) and disengages at $T_J=130^{\circ}C$ (typical).

ESD Ratings

Item	Description	Value	Unit
	Human Body Model (HBM)		
V _(ESD-HBM)	ANSI/ESDA/JEDEC JS-001-2014	± 2000	V
	Classification, Class: 2		
	Charged Device Mode (CDM)		
V _(ESD-CDM)	ANSI/ESDA/JEDEC JS-002-2014	± 200	V
	Classification, Class: C0b		
	JEDEC STANDARD NO.78E APRIL 2016		
ILATCH-UP	Temperature Classification,	±150	mA
	Class: I		

Recommended Operating Conditions

Item	Min	Max	Unit
Operating junction temperature ⁽¹⁾	-40	125	°C
Operating temperature range	-40	85	°C
Input voltage V _{IN}	2.4	5.5	V

Note (1): All limits specified at room temperature ($T_A = 25^{\circ}C$) unless otherwise specified. All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).



Thermal Information

Item	Description	Value	Unit
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾	180	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	130	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	45	°C/W
ΨJT	Junction-to-top characterization parameter	35	°C/W
Ψјв	Junction-to-board characterization parameter	45	°C/W

Note (1): The package thermal impedance is calculated in accordance to JESD 51-7.

Note (2): Thermal Resistances were simulated on a 4-layer, JEDEC board.

Electrical Characteristics⁽¹⁾

 $(V_{IN} = 5V, C_L = 1\mu F, \text{ per channel}, T_A = 25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min	Тур.	Max	Unit
Input Voltage Range	V _{IN}		2.4		5.5	V
Shutdown Input Current	I _{SHDN}	Open load, IC Disabled		0.6	1	μΑ
Quiescent Supply Current	IQ	Open load, IC Enabled		20		μΑ
FET RON	R _{DS(ON)1}			80		mΩ
ENB Rising Threshold	V _{ENB(H)}		1.2			V
ENB Falling Threshold	V _{ENB(L)}				0.8	V
ENB Leakage	I _{ENB}	$V_{ENB}=5.5V$			1	μΑ
IN UVLO Threshold	V _{IN,UVLO}				2.3	V
IN UVLO Hysteresis	V _{IN,HYS}			0.1		V
	I _{LIM}	RSET=10 kΩ	0.75	1	1.25	А
Current Limit	I _{LIM(MIN)}			0.4		А
	I _{LIM(MAX)}			2		А
Trip Current	I _{Trip}			1.25		А
Turn-ON Time ⁽²⁾	T _{ON}	$R_L=10\Omega$, $C_L=1uF$		120		μS
Turn-OFF Time ⁽²⁾	T _{OFF}	$R_L=10\Omega$, $C_L=1uF$		10		μS
OUT Shutdown Discharge Resistance	R _{DIS}			150		Ω
Thermal Shutdown Temperature	T _{SD}			130		°C
Thermal Shutdown Hysteresis	T _{HYS}			20		°C

Note (1): The device is not guaranteed to function outside its operating conditions.

Note (2): Measured from (50%) EN signal to (90%) output signal.



Typical Performance Characteristics ^{(1) (2)}

Note (1): Performance waveforms are tested on the evaluation board. Note (2): $V_{IN} = 5V$, $C_{OUT} = 1\mu F$, $T_A = +25^{\circ}C$, unless otherwise noted.



Turn off Delay vs. Input Voltage

VEN=5V, RLOAD=5.5 Ω

V_{EN} =5V, R_{LOAD} =5.5 Ω





Supply Current, Output Enabled vs.

RY2121

Input Voltage

VEN = 5V



Supply Current, Output Disabled vs.

Input Voltage

VEN = 0V



Static Drain-Source On-State Resistance vs. Input Voltage VEN = 5V, I_{LOAD}=0.5A



Input to Output Voltage vs.

Load Current

Ven = 5V



Current Limit vs. Input Voltage



Threshold Trip Current vs. Input Voltage



Current Limit vs. RSET





Turn on Delay Rise Time

Turn off Delay Fall Time

Threshold Trip Current with Ramped Load Enabled Device

RY2121

VEN = 5V, RLOAD=5 Ω







 1Ω Load Connected to Enabled Device

Short Circuit Current, Device Enabled into Short



Current Limit vs. R_{SET}







Functional Block Diagram



Block Diagram

Functions Description

Current Limit

The RY2121 provides a constant current limit that can be programmed by an external resistor. Once the device reaches its current limit threshold, the internal circuit regulates the gate voltage to hold the current in the power MOSFET constant. Below table can be taken as a reference to choose R_{SET} to set the current limit threshold. Following table are all tested with 5V input as the test condition

$R_{SET}(k\Omega)$	Typical Current Limit (mA)
4.99	2000
5.1	1900
5.76	1800
6.49	1600
8.87	1200
9.53	1100
10	1000
12	900
30	600
50	350
100	250



Over Current

When the load exceeds trip current (minimum threshold current triggering constant-current mode) or short circuited, RY2121 switches into to constant-current mode (current limit value). RY2121 will be shut down only if the overcurrent condition stays long enough to trigger thermal protection.

Trigger overcurrent protection for different overload conditions occurring in applications:

1) The output has been shorted or overloaded before the device is enabled or input applied. RY2121 detects the short or overload and immediately switches into a constant-current mode.

2) A short or an overload occurs after the device is enabled. The device switches into constant current mode after the current-limit circuit has been tripped (reached the trip current threshold). However, high current may flow for a short period of time before the current-limit circuit can react.

3) Output current has been gradually increased beyond the recommended operating current. The load current rises until the trip current threshold is reached or until the thermal limit of the device is exceeded. Once the trip threshold has been reached, the device switches into its constant-current mode.

Thermal Protection

If the current limit block starts to regulate the output current, the power loss on power MOSFET will cause the IC temperature rise. The die temperature is internally monitored until the thermal limit is reached. Once this temperature is reached, the switch will turn off to allow the chip to cool until the over temperature fault remove. The over temperature threshold is 130°C and hysteresis is 20°C.

Under-voltage Lockout (UVLO)

This circuit is used to monitor the input voltage to ensure that the RY2121 is operating correctly. This UVLO circuit also ensures that there is no operation until the input voltage reaches the minimum spec.

Output Discharge

RY2121 has output discharge function. It can discharge the output capacitor by internal pulldown resistance during shutdown.



Package Description





NOTE:

NOTE: 1. CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS. 2. PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. 3. PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. 4. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX. 5. DRAWING CONFORMS TO JEDEC MS ON 2 VARIATION PA

5. DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA. 6. DRAWING IS NOT TO SCALE.